

MOSFET OPTIMOS PWR-TRANS N-CH 55V 30A 13mOhms

Manufacturers	<u>Infinion Technologies Corporation</u>
Package/Case	TO-252
Product Type	Transistors
RoHS	Rohs
Lifecycle	



Images are for reference only

Please submit RFQ for IPD30N06S2L-13 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

IPD30N06S2L-13 is a type of N-channel MOSFET transistor with a voltage rating of 60V and a maximum current of 30A. It is commonly used in power switching applications due to its low on-resistance and high current-handling capabilities.

Features

- Low on-resistance
- Fast switching speed
- Low gate charge
- Avalanche ruggedness
- RoHS compliant

Application

- Power supplies
- DC-DC converters
- Motor control
- Lighting ballasts
- Audio amplifiers

Shift : A/B/C
Strn : 1/2
Reel No:

0	1	2	3	4	5	6	7	8	9
0	1	2	3	4	5	6	7	8	9

Infineon

IPD30N06S2L-13

(1P): SP001061280



(9D): 1805



(Q): 1805



(X): 97819153



Diffused in MALAYSIA, Assembled in MALAYSIA



Level/Temp: 1/260



PS5LPLV5180203

Related Products



[IPP60R070CFD7](#)

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TO-220-3



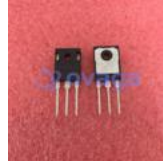
[IPB180N06S4-H1](#)

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